2013년 2월 4일(월)~6일(수) / 웰리힐리파크 (구, 성우리조트)

우) 302-120 대전광역시 서구 둔산동 1018번지 대한빌딩 5층 / 담당. 최은영 팀장, 김아영 TEL: (042) 472 -7461 FAX: (042) 472 -7459 E-mail: kcs@cosar.or.kr

Room J

골드홀 (본관, 5층)

2013년 2월 6일(수) 12:45-14:10 [WP1] Poster 3

WP1-1	12:45-14:10	Improvement in Performance of 380nm Ultra Violet Light Emitting Diodes Employing Nano-Scale SiO2 Patterned n-type GaN Substrate Hyo Won Seo <sup>1</sup> , Min Sung Jo <sup>1</sup> , Wael Z. Tawfik <sup>1</sup> , Seo Jung Bae <sup>1</sup> , Young Boo Moon <sup>2</sup> , and June Key Lee <sup>1</sup> <sup>1</sup> Interdisciplinary Program of Photonic Engineering, Chonnam National University, <sup>2</sup> THE LEDs co. Ltd
WP1-2	12:45-14:10	Enhancement of Blue InGaN/GaN Multi-Quantum-Well Light-Emitting Diodes Characteristics by Applying External Tensile Stress Wael Z. Tawfik, Ju Hui Song, Hyo Won Seo, Seo Jung Bae, and June Key Lee Interdisciplinary Program of Photonic Engineering, Chonnam National University
WP1-3	12:45-14:10	Systematic Band Gap Engineering of Tandem CIGS Absorption Layer by using Sputtering and Selenization System San Kang, Seong-Un Park, Byung-June Baek, Rahul Sharma, Jae-Kwan Sim, and Cheul-Ro Lee Research Center for Advanced Materials Development, Chonbuk National University
WP1-4	12:45-14:10	Thermodynamic Consideration on Facet Formation of Si <sub>0.15</sub> Ge <sub>0.85</sub> Nanowire Byongju Kim, Sun-Wook Kim, Jeong-Hoon Kim, Hyunchul Jang, and Dae-Hong Ko Department of Materials Science and Engineering, Yonsei University
WP1-5	12:45-14:10	A Study on Surface Plasmon Resonance with Gold Nanoparticles onto the CIGS Absorption Layer Seong-Un Park, San Kang, Byung-June Baek, Rahul Sharma, Jae-Kwan Sim, and Cheul-Ro Lee School of Advanced Materials Engineering, College of Engineering, Research Center for Advanced Materials Development, Chonbuk National University
WP1-6	12:45-14:10	Rapid Synthesis of Few-Layer Graphene with a Controllable Thickness Jae Hwan Chu <sup>1</sup> , Jinsung Kwak <sup>1</sup> , Tae-Yang Kwon <sup>1</sup> , Soon-Dong Park <sup>1</sup> , Heungseok Go <sup>2</sup> , Sung Youb Kim <sup>1</sup> , Kibog Park <sup>2</sup> , and Soon-Yong Kwon <sup>1,2</sup> <sup>1</sup> School of Mechanical and Advanced Materials Engineering, Ulsan National Institute of Science and Technology, <sup>2</sup> School of Electrical and Computer Engineering, Ulsan National Institute of Science and Technology

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WP1-7	12:45-14:10	Si 기판상에 GaSb 화합물 반도체 성장 및 연구 배민환 <sup>1,2</sup> , 송진동 <sup>1</sup> , 이은혜 <sup>1</sup> , 연규혁 <sup>1</sup> , 김준영 <sup>1</sup> , 오현지 <sup>1</sup> , 최원준 <sup>1</sup> , 박원일 <sup>2</sup> <sup>1</sup> 한국과학기술연구원 광전융합시스템연구단, <sup>2</sup> 한양대학교 나노전자재료실험실
WP1-8	12:45-14:10	<b>Droplet Epitaxy 법을 이용한 GaAs Quantum Ring 형성</b> 이은혜 <sup>1,2</sup> , 송진동 <sup>1</sup> , 김지훈 <sup>1</sup> , 김수연 <sup>1</sup> , 배민환 <sup>1</sup> , 연규혁 <sup>1</sup> , 김준영 <sup>1</sup> , 한일기 <sup>1</sup> , 장수경 <sup>2</sup> , 김종수 <sup>3</sup> <sup>1</sup> 한국과학기술연구원 광전융합시스템연구단, <sup>2</sup> 연세대학교 물리학과, <sup>3</sup> 영남대학교 물리학과
WP1-9	12:45-14:10	Arsenic 주입을 Pulse로 준 Ga assisted GaAs Nanowire 성장 방법 연규혁 <sup>1,2</sup> , 이은혜 <sup>2</sup> , 김수연 <sup>2</sup> , 송진동 <sup>1,2</sup> <sup>1</sup> 과학기술연합대학원대학교 나노전자소자공학, <sup>2</sup> 한국과학기술연구원 광전융합시스템연구단
WP1-10	12:45-14:10	Development of Nanolaminated Single Gas Diffusion Barrier Layer by Neutral Beam Assisted Sputtering Process YunSung Jang and MunPyo Hong Department of Display Semiconductor Physics, Korea University
WP1-11	12:45-14:00	Effect of Negative Oxygen Ions Accelerated by Dc Self-Bias on Amorphous InGaZnO Thin Film Transistors Doohyun Kim, Soobok Yoon, and MunPyo Hong Department of Display and Semiconductor Physics, Korea University
WP1-12	12:45-14:00	New Approaches for Extremely High Doping and High Crystal Fraction in the Mixed Phase Nano-Crystal Silicon Thin Film by Near Room Temperature Deposition Process with Neutral Beam Assisted CVD  Jin Nyoung Jang <sup>1</sup> , Dong Hyeok Lee <sup>1</sup> , Hyun Wook So <sup>1</sup> , Chang-Sun Park <sup>2</sup> , Hyung-Ho Park <sup>2</sup> , and MunPyo Hong <sup>1</sup> ¹Department of Display and Semiconductor Physics, Korea University ²Department of Materials Science and Engineering, Yonsei University
WP1-13	12:45-14:10	Fine Tuning of Termination Capacitance and Neutral Beam Energy Dependent Controlling of Oxygen Contents in Undoped Nano-Crystal Silicon Thin Film by using Neutral Beam Assisted ICP CVD DongHyeok Lee, JinNyoung Jang, HyunWook So, and MunPyo Hong Department of Display and Semiconductor Physics, Korea University
WP1-14	12:45-14:10	Study on the Seasoning Effect for Amorphous In-Ga-Zn-O Thin Film Transistors with Soluble Hybrid Passivation Soobok Yoon, Doohyun Kim, and MunPyo Hong Department of Display and Semiconductor Physics, Korea University
WP1-15	12:45-14:10	Sensing Performance Improvement of Dual-Gate Ion-Sensitive Field- Effect Transistors on Ultra-thin Body

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		Hyun-June Jang and Won-Ju Cho Department of Electronic Materials Engineering, Kwangwoon University
WP1-16	12:45-14:10	Dual-Gate Operation에 의한 Engineered Sensing Membrane의 Sensing 특성 개선 박진권, 조원주 광운대학교 전자재료공학과
WP1-17	12:45-14:10	Thickness Dependence of HfO <sub>2</sub> Sensing Membrane in Electrolyte-Insulator-Semiconductor (EIS) Structure using a Solution Process이인규, 조원주 광운대학교 전자재료공학과
WP1-18	12:45-14:10	Silicon Nano Structured Field Effect Transistor Based pH Sensor Array Yeong Tai Seo <sup>1,2</sup> , Kangwon Cho <sup>2</sup> , Hyeyoon Kim <sup>2</sup> , Jin-Ah Yang <sup>2</sup> , Min-Ho Lee <sup>2</sup> , Kook-Nyung Lee <sup>2</sup> , Woo-Kyeong Seong <sup>2</sup> , and Yong-Kweon Kim <sup>1</sup> <sup>1</sup> School of Electrical Engineering and Computer Science, Seoul National University, <sup>2</sup> Korea Electronics Technology Institute
WP1-19	12:45-14:10	Study of Touch Sensing Characteristics in PVDF-TrFE/MoS <sub>2</sub> Field-Effect Transistors 박우진 <sup>1</sup> , 양진호 <sup>1</sup> , 강창구 <sup>1</sup> , 조천흠 <sup>1</sup> , 이상철 <sup>1</sup> , 임성관 <sup>1</sup> , 김용훈 <sup>1</sup> , 이상경 <sup>1</sup> , 강수철 <sup>1</sup> , 홍웅기 <sup>2</sup> , 이병훈 <sup>1</sup> <sup>1</sup> 광주과학기술원 신소재공학부, <sup>2</sup> 한국기초과학지원연구원
WP1-20	12:45-14:10	A Multi-Wavelength Detectable AlGaN/GaN MIS UV Photodetector Chang-Ju Lee, Chul-Ho Won, Jung-Hee Lee, and Sung-Ho Hahm School of Electrical Engineering and Computer Science, Kyungpook National University
WP1-21	12:45-14:10	Sensing Capability Enhancement and Thermal Insulation Improvement for High Sensitivity Microfluidic Chip Calorimeter Joonyoung Koh <sup>1</sup> , <sup>2,3</sup> , Jung. H. Shin <sup>1,2</sup> , and Wonhee Lee <sup>1</sup> , <sup>2,3</sup> <sup>1</sup> Graduate School of Nanoscience and Technology, KAIST, <sup>2</sup> Department of Physics, KAIST, <sup>3</sup> Institute for the Nanocentury, KAIST
WP1-22	12:45-14:10	Nanowire Ion-Sensitive Field Effect Transistor for Uric Acid Detection Unsang Lee <sup>1</sup> , Taiuk Rim <sup>2</sup> , Kihyun Kim <sup>2</sup> , Nanki Hong <sup>2</sup> , Chanoh Park <sup>1</sup> , M. Jamal Deen <sup>1,3</sup> , and Jeong-Soo Lee <sup>1,2</sup> <sup>1</sup> Division of IT-Convergence Engineering, Pohang University of Science and Technology, <sup>2</sup> Department of Electrical Engineering, Pohang University of Science and Technology, <sup>3</sup> ECE Department, McMaster University
WP1-23	12:45-14:10	Effects of Forming Voltage in Pt/Si <sub>3</sub> N <sub>4</sub> /p <sup>+</sup> -Si RRAM Devices Sungjun Kim <sup>1</sup> , Sunghun Jung <sup>1</sup> , Kyung-Chang Ryoo <sup>2</sup> , Jeong-Hoon Oh <sup>2</sup> , and Byung-Gook Park <sup>1</sup> <sup>1</sup> Inter-university Semiconductor Research Center (ISRC) and School of Electrical Engineering and Computer Science, Seoul National University, <sup>2</sup> DRAM Process Architecture Team, Memory Division, Semiconductor

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		Business, Samsung Electronics Co., Ltd.
WP1-24	12:45-14:10	Bipolar Resistive Switching Characteristics of Solution-Processed AlO <sub>x</sub> Thin Films for Non-Volatile Memory Application Chang-Wan Kim and Won-Ju Cho Department of Electronic Materials Engineering, Kwangwoon University
WP1-25	12:45-14:10	Analytical Model of Static Noise Margin Variationin 6-T SRAM with Double-Gate FinFETs  Boung-Jun Lee and Ji-Woon Yang  Department of Electronics and Information Engineering, Korea University
WP1-26	12:45-14:10	The Study of Ag Doping Effects on Phase Change Characteristics of GeTe Jin Hwan Jeong, Su Bin An, and Doo Jin Choi Department of Material Science and Engineering, Yonsei University
WP1-27	12:45-14:10	Solution Process Based Oxidizable Metal Layer Free GeSe ReRAM on p <sup>+</sup> -Si Electrode 남기현, 이동현, 김장한, 소준환, 조원주, 정홍배 광운대학교 전자재료공학과
WP1-28	12:45-14:10	Threshold and Bipolar Resistive Switching of Pt-Fe <sub>2</sub> O <sub>3</sub> Core-Shell Nanoparticle Assembly Yoon-Jae Baek <sup>1</sup> , Quanli Hu <sup>2</sup> , Hyung Jun Kim <sup>1</sup> , Seung Chang Lee <sup>1</sup> , Jae-Deuk Kim <sup>1</sup> , Jin Yong Lee <sup>1</sup> , Chi Jung Kang <sup>2,3</sup> , and Tae-Sik Yoon <sup>1,2</sup> <sup>1</sup> Department of Materials Science and Engineering, Myongji University, <sup>2</sup> Department of Nano Science and Engineering, Myongji University, <sup>3</sup> Department of Physics, Myongji University
WP1-29	12:45-14:10	Cell Area Effect on Read Failure Problem Disturbing Nonvolatile Memory Applications of Conductive Filament-Type Resistive Switching Memory Devices Jung-Kyu Lee <sup>1</sup> , Byeong-In Choe <sup>1</sup> , Jinwon Park <sup>2</sup> , Sung-Woong Chung <sup>2</sup> , Jae Sung Roh <sup>2</sup> , Sung-Joo Hong <sup>2</sup> , Byung-Gook Park <sup>1</sup> , and Jong-Ho Lee <sup>1</sup> <sup>1</sup> School of Electrical Engineering and Computer Science and Inter-University Semiconductor Research Center, Seoul National University, <sup>2</sup> R&D Division, SK Hynix Inc.
WP1-30	12:45-14:10	Improved Resistive Switching Characteristics Using Solution-Processed $Ta_2O_5/HfO_2$ Double Layer ReRAM 장기현, 조원주 광운대학교 전자재료 공학과
WP1-31	12:45-14:10	The Analysis of HBr Plasma Instability using Balanced Capacitor in Inductively Coupled Plasma Source 엄정환, 강태균 삼성전자 반도체사업부

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WP1-32	12:45-14:10	Behavioral Model with Intermediate States for Unipolar Resistive Memories Young Su Kim, and Kyeong-Sik Min School of Electrical Engineering, Kookmin University
WP1-33	12:45-14:10	A Programmable-N Frequency Divider for Wideband RF PLL Hogil Kim, Dongsik Kim, and Sanghoon Chai Department of Electronic Engineering, Hoseo University
WP1-34	12:45-14:10	최대/최소 시비율 제어기를 포함하고 빠른 시간응답을 갖는 디지털 DC DC 변환기 설계 오택준, 황인철 강원대학교 일반대학원 전기전자공학과
WP1-35	12:45-14:10	Area-Efficient a-Si Gate Driver Circuit with Shared Driving Node 안소라, 김지아, 신형순, 이승준 이화여자대학교 전자공학과
WP1-36	12:45-14:10	디지털 커패시턴스 모듈레이션을 이용한 다중 출력 스위치 커패시터 DC-DC 컨버터 이정윤, 윤선우, 박상용, 이진현, 백동현 중앙대학교 전자전기공학과
WP1-37	12:45-14:10	<b>근거리 무선 통신을 위한 주파수 합성기의 연구</b> 정명호, 문용 숭실대학교 전자공학과
WP1-38	12:45-14:10	Innovative Verification Methods in the Era of 1B SoCs NamPhil Jo <sup>1</sup> , HyunWoo Koh <sup>1</sup> , DaeSeo Cha <sup>1</sup> , and Karthik Kothandapani <sup>2</sup> <sup>1</sup> Samsung Electronics Co., Ltd., <sup>2</sup> Cadence Design Systems Inc.
WP1-39	12:45-14:10	Channel Estimation Algorithm and Implementation with FPGA for Low Complexity WBAN System Hyunsub Kim, Minjoon Kim, and Jaeseok Kim IT-SoC Research Lab., Yonsei University
WP1-40	12:45-14:10	Embryonic Cell Based Zigbee Architecture for Self-Healing 백승규, 김병수, 왕규열, 정진용 인하대학교 정보통신공학부
WP1-41	12:45-14:10	<b>방향성에 강인한 물체인식 및 추적 알고리즘 구현</b> 허훈, 경규택, 곽재창, 이광엽 서경대학교 전자컴퓨터공학과